

# RJK0660DPA

# Silicon N Channel Power MOS FET Power Switching

R07DS0346EJ0100 Rev.1.00 Apr 06, 2011

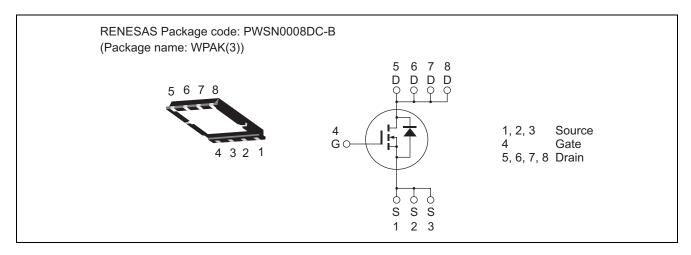
#### **Features**

- High speed switching
- Low drive current
- High density mounting
- Low on-resistance

 $R_{DS(on)} = 4.2 \text{ m}\Omega \text{ typ. (at } V_{GS} = 10 \text{ V})$ 

- Pb-free
- Halogen-free

#### **Outline**



#### **Absolute Maximum Ratings**

 $(Ta = 25^{\circ}C)$ 

Item	Symbol	Ratings	Unit
Drain to source voltage	V <sub>DSS</sub>	60	V
Gate to source voltage	$V_{GSS}$	±20	V
Drain current	I <sub>D</sub>	40	А
Drain peak current	I <sub>D(pulse)</sub> Note1	160	А
Body-drain diode reverse drain current	I <sub>DR</sub>	40	А
Avalanche current	I <sub>AP</sub> Note 2	20	А
Avalanche energy	E <sub>AR</sub> Note 2	30	mJ
Channel dissipation	Pch Note3	65	W
Channel to case thermal impedance	θch-c Note3	1.93	°C/W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. PW  $\leq$  10  $\mu$ s, duty cycle  $\leq$  1%

- 2. Value at Tch = 25°C, Rg  $\geq$  50  $\Omega$
- 3.  $Tc = 25^{\circ}C$

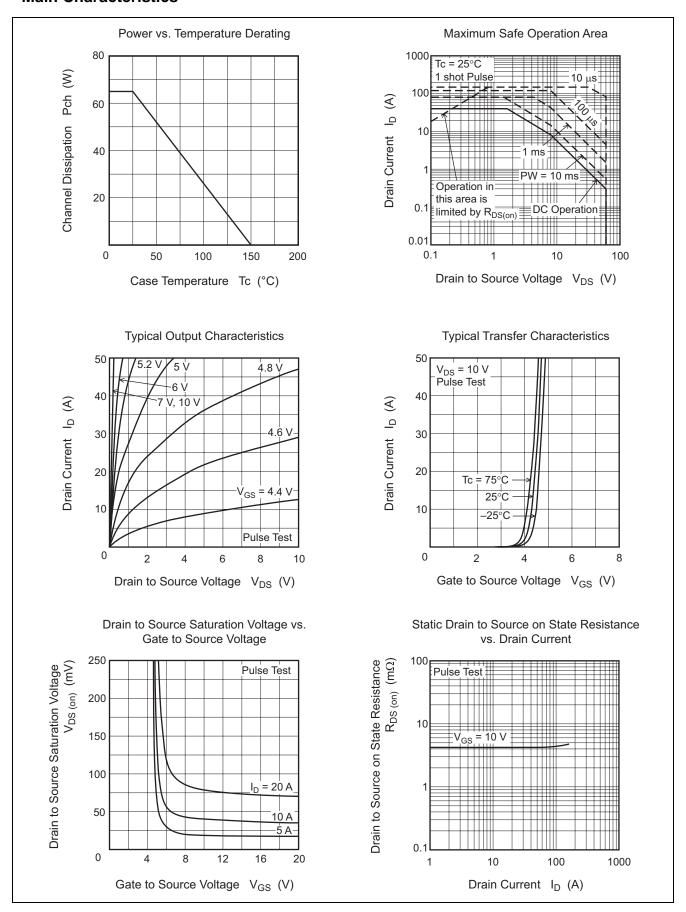
## **Electrical Characteristics**

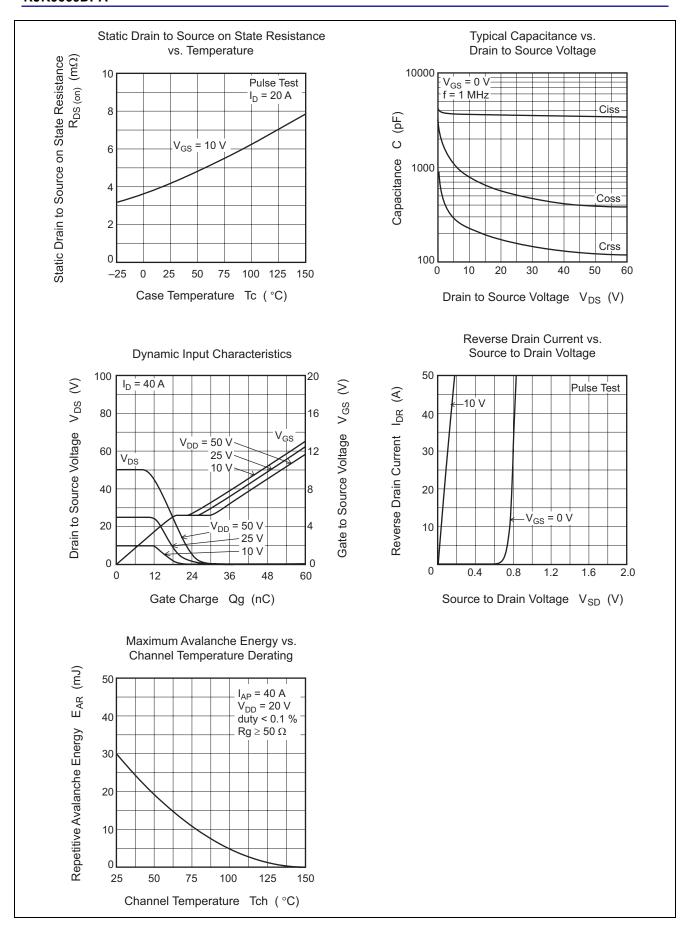
 $(Ta = 25^{\circ}C)$ 

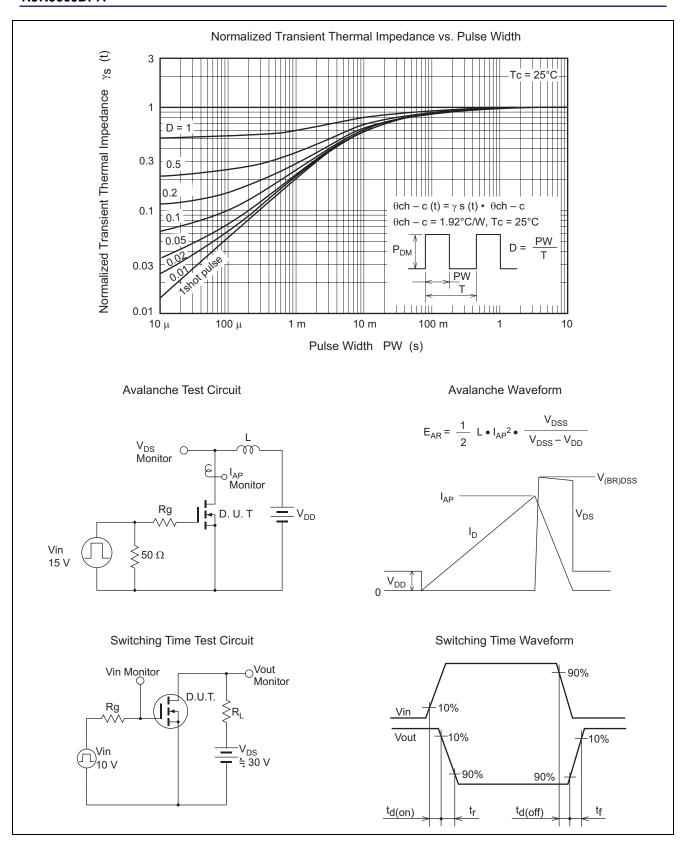
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	60	_	_	V	$I_D = 10 \text{ mA}, V_{GS} = 0 \text{ V}$
Gate to source leak current	$I_{GSS}$	_	_	±0.1	μΑ	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$
Zero gate voltage drain current	I <sub>DSS</sub>	_	_	1	μΑ	$V_{DS} = 60 \text{ V}, V_{GS} = 0 \text{ V}$
Gate to source cutoff voltage	$V_{GS(off)}$	2.0	_	4.0	V	$V_{DS} = 10 \text{ V}, I_{D} = 1 \text{ mA}$
Static drain to source on state resistance	R <sub>DS(on)</sub>	_	4.2	5.1	mΩ	$I_D = 20 \text{ A}, V_{GS} = 10 \text{ V}^{\text{Note4}}$
Forward transfer admittance	y <sub>fs</sub>	_	60	_	S	$I_D = 20 \text{ A}, V_{DS} = 10 \text{ V}^{\text{Note4}}$
Input capacitance	Ciss	_	3600	_	pF	$V_{DS} = 10 \text{ V}, V_{GS} = 0 \text{ V},$
Output capacitance	Coss	_	830	_	pF	f = 1 MHz
Reverse transfer capacitance	Crss	_	230	_	pF	
Gate Resistance	Rg	_	1.1	_	Ω	
Total gate charge	Qg	_	45	_	nC	$V_{DD} = 25 \text{ V}, V_{GS} = 10 \text{ V},$ $I_{D} = 40 \text{ A}$
Gate to source charge	Qgs	_	20	_	nC	
Gate to drain charge	Qgd	_	7.5	_	nC	
Turn-on delay time	t <sub>d(on)</sub>	_	18	_	ns	$V_{GS} = 10 \text{ V}, I_D = 20 \text{ A},$
Rise time	t <sub>r</sub>	_	14	_	ns	$V_{DD} \cong 30 \text{ V, } R_L = 1.5 \Omega,$ $Rg = 4.7 \Omega$
Turn-off delay time	t <sub>d(off)</sub>	_	43	_	ns	
Fall time	t <sub>f</sub>	_	11	_	ns	
Body-drain diode forward voltage	$V_{DF}$	_	0.8	1.1	V	I <sub>F</sub> = 40 A, V <sub>GS</sub> = 0 V Note4
Body-drain diode reverse recovery time	t <sub>rr</sub>	_	47	_	ns	I <sub>F</sub> = 40 A, V <sub>GS</sub> = 0 V
						di <sub>F</sub> / dt = 100 A/ μs

Notes: 4. Pulse test

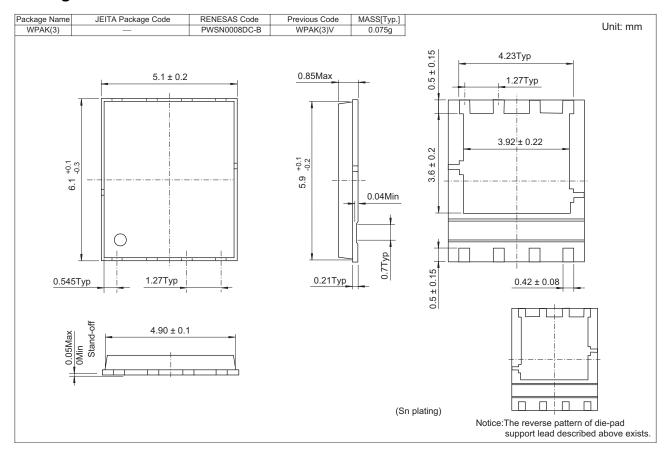
#### **Main Characteristics**







## **Package Dimensions**



# **Ordering Information**

Orderable Part No.	Quantity	Shipping Container
RJK0660DPA-00-J5A	3000 pcs	Taping

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